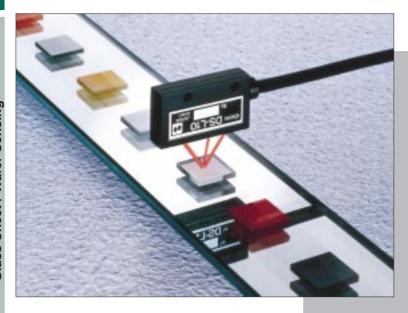
Wafer Detection Sensor



Sensing Various Objects at Constant Distance Using 'Differential Distance Discrimination Method'

Optimum for Wafer Detection

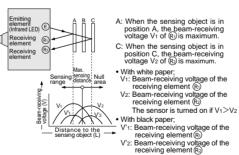
The sensor can reliably detect wafers irrespective of their glossiness or color.



Reliable Fixed-focus Sensing

The differential distance discrimination method using two independent beamreceiving elements enables accurate fixed-focus sensing which can discriminate up to a difference of one sheet of paper.

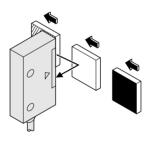
Differential distance discrimination method:



The sensor is turned on if V1>V2

A Variety of Objects

Objects ranging from black to glossy, irrespective of their reflectivity, can be reliably detected at almost a constant distance due to the differential distance discrimination method.



High Performance

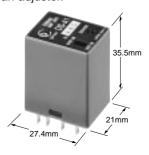
The repeatability is $10 \mu m$ or less. Moreover, it can detect a hair-like fine copper wire (ϕ 50 μ m).

Extremely Stable Sensing

Regardless of temperature drift or voltage fluctuation, the differential distance discrimination method ensures stable detection.

Miniature Amplifier

The amplifier has dimensions similar to a miniature relay, which makes its handling simple. Further, it incorporates an easily visible operation indicator and a fine span adjuster.

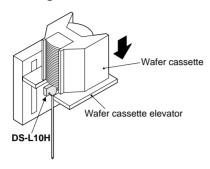


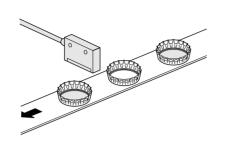
APPLICATIONS

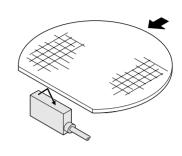
Detecting wafers in cassette



Detecting passage of wafer







ORDER GUIDE

Sensor heads

ochsor neads			
Туре	Appearance	Sensing range (Note)	Model No.
Side sensing		Maximum sensing distance	DS-L10
nsing		2 to 8mm Optimum sensing range	DS-L10H
Top sensing		Maximum sensing distance 30mm 5 to 24mm Optimum sensing range	DS-L24H

Note: The sensing range gives the setting distance for presence detection. For sensing minute difference, use by setting at the maximum sensing distance.

Amplifier

Ampimer			
Туре	Appearance	Model No.	
Dedicated amplifier		DS-A1	

DS

SPECIFICATIONS

Sensor heads

Туре		Fixed-focus (for wafer sensing)			
		Side sensing	Side sensing Top se		
Ite	m Model No.	DS-L10	DS-L10H	DS-L24H	
Applicable amplifier			DS-A1		
Sensing range (Note 1)		2 to 8mm	2 to 8mm (Note 2)		
Max. sensing distance		10.0 ± 1.5m	10.0 ± 1.5mm (Note 2)		
Min. sensing object			ϕ 0.05mm copper wire (Setting distance: 5mm with no background)		
Hysteresis		100 <i>μ</i> m	100 µm or less		
Repeatability				Along sensing axis: 10 µm or less Perpendicular to sensing axis: 50 µm or less (setting distance: 14mm)	
	Ambient temperature	0 to \pm 50°C (No dew condensation), Storage: \pm 20 t		to + 70°C	
ance	Ambient humidity	35 to 85% RH, Storage: 35 to 85% RH			
resistance	Ambient illuminance	Sunlight: 11,000 ℓ x at the light-receiving face Incandescent light: 3,500 ℓ x at the light-receiving face		Incandescent light: 70,000 ℓ x at the light-receiving face	
enta	Voltage withstandability	1,500V AC for one min. between all supply terminals connected to		together and enclosure	
Environmental	Insulation resistance	20MΩ, or more, with 500V DC	20 Μ Ω , or more, with 500V DC megger between all supply terminals connected together and enclosure		
Envi	Vibration resistance	10 to 55Hz frequency, 1.5mm amplitude in X, Y and Z directions for two hours		ns for two hours each	
	Shock resistance	500m/s ² acceleration (50G approx.) in X, Y and Z directions for three times each			
Emitting element		Infrared LED (modulated)			
Temperature characteristics		Over ambient temperature range 0 to \pm 50°C: within \pm 1% of sensing range at 20°C			
Material		Enclosure: ABS			
Cable		0.08mm² composite 3-core shielded cable, 3m long			
Cable extension		Extension up to total 5m is possible with an equivalent cable.			
Weight		80g approx.			
Acc	essory	MS-DS-1 (Sensor head mounting bracket): 1 set			

SUNX

Notes: 1) The sensing range gives the setting distance for presence detection. For sensing minute difference, use by setting at the maximum sensing distance.

2) The sensing range and the maximum sensing distance are specified for white non-glossy paper (**DS-L10** and **DS-L10H**: 20 × 20mm, **DS-L24H**: 50 × 50mm) as the object.

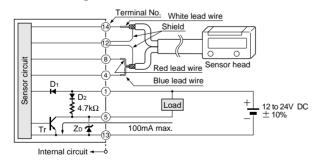
SPECIFICATIONS

Amplifier

	Туре	Dedicated amplifier	
Ite	m Model No.	DS-A1	
Applicable sensor heads		DS-L10, DS-L10H, DS-L24H	
Supply voltage		12 to 24V DC ± 10% Ripple P-P 10% or less	
Current consumption		40mA or less	
Output		NPN transistor universal • Maximum sink current: 100mA • Residual voltage: 1V or less (at 100mA sink current) 0.4V or less (at 16mA sink current)	
	Output operation	Switchable either Light-ON or Dark-ON with the operation mode switch	
	Short-circuit protection Incorporated		
Response time		3ms or less	
Ор	eration indicator	Red LED (lights up when the output is ON)	
Span adjuster		Continuously variable adjuster (enables fine adjustment of the maximum sensing distance)	
Φ	Ambient temperature	0 to \pm 50°C (No dew condensation), Storage: $-$ 20 to \pm 70°C	
tanc	Ambient humidity	35 to 85% RH, Storage: 35 to 85% RH	
resis	Noise immunity	Power line: 200Vp, $1\mu s$ pulse width; Radiation: 1,300Vp, $1\mu s$ pulse width (with noise simulator)	
ntal	Voltage withstandability	1,500V AC for one min. between all supply terminals connected together and enclosure	
nme	Insulation resistance	$20M\Omega$, or more, with 500V DC megger between all supply terminals connected together and enclosure	
Environmental resistance	Vibration resistance	10 to 55Hz frequency, 1.5mm amplitude in X, Y and Z directions for two hours each	
	Shock resistance	100m/s ² acceleration (10G approx.) in X, Y and Z directions for three times each	
Ma	terial	Enclosure: Polycarbonate, Terminal base: PBT	
We	ight	15g approx.	
Accessory		Adjusting screwdriver: 1 No.	

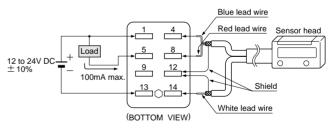
I/O CIRCUIT AND WIRING DIAGRAMS

I/O circuit diagram



. D1: Reverse supply polarity protection diode D2: Reverse current prevention diode ZD: Surge absorption zener diode Tr: NPN output transistor

Wiring diagram

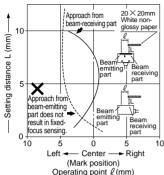


SENSING CHARACTERISTICS (TYPICAL)

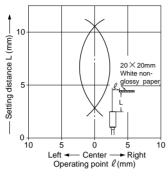
DS-L10 DS-L10H

Sensing fields

Vertical direction



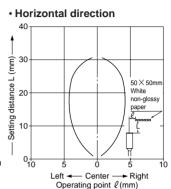
· Horizontal direction



DS-L24H

I eft ◄

Sensing fields Vertical direction 40 (mm) 30 50 × 50mm Setting distance distance 20 White non-glossy pape 20 Approach from beam-emitting HBea rece part part does not esult in fixed



PRECAUTIONS FOR PROPER USE

Refer to P.820~ for general precautions.



This product is not a safety sensor. Its use is not intended or designed to protect life and prevent body injury or property damage from dangerous parts of machinery. It is a normal object detection sensor.

Wiring

· Use a commercially available miniature relay terminal socket to connect DS-A1.

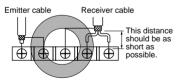
*Applicable terminal socket: AP3822K (manufactured by Matsushita Electric Works), etc.

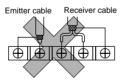
• If the attached sensor head cable needs to be extended,

use appropriate shielded cables and limit the extension to

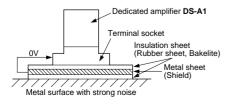
Emitter cable: shielded cable with one conductor Receiver cable: shielded cable with two conductors

Extension with one shielded cable containing both the emitter cable and the receiver cable is prohibited. If a joint terminal is used for extension, separate the conductors of the emitter cable and the receiver cable as far as possible as shown below.





• In case the sensor is used in a noisy place, take care of the surrounding noise. Do not run the sensor head cable along any high voltage or power cable or put them in the same raceway. In fact, separate them as far as possible. Further, if the DS-A1 amplifier is to be mounted on a metal surface, devise a shield as shown in the figure below and connect it to 0V.



Setting of sensor head

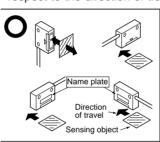
Center -

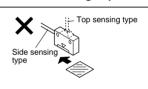
(Mark position)

Operating point ℓ (mm)

→ Right

· Take care of the mounting direction of the sensor head with respect to the direction of travel of the sensing object.





Do not mount the sensor head in a direction such that the sensing object approaches from the direction shown above.

Note: Take care of the positions of the \triangle mark and the name plate on the sensor head to recognize the orientation.

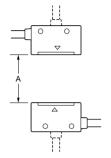
• The tightening torque of the sensor head should be 0.29N·m or less.

Refer to P.820~ for general precautions.

PRECAUTIONS FOR PROPER USE

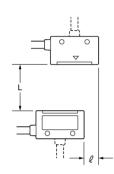
· When mounting two sensor heads face to face, the minimum separation distance should be as shown below to avoid mutual interference.

Non-twisted facing

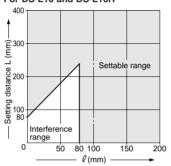


DS-L10 DS-L10H		DS-L24H	
Α	30mm or more	120mm or more	

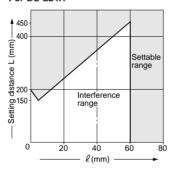
Twisted facing



For DS-L10 and DS-L10H



For DS-L24H



Setting of sensing distance

- · Allow an adjustable range of 5 to 12mm (DS-L24H: 10 to 35mm) from the sensor head to the sensing object when mounting the sensor head.
- *The attached mounting bracket has an adjustment range of 7mm.
- · If the distance between the sensing object and the background is 7mm or more (DS-L24H: 25mm or more), set the sensing distance between the sensor head and the sensing object to 7mm approx. (DS-L24H: 25mm approx.) (span adjuster at maximum).
- · To detect a small or a dark object, the optimum distance between the sensor head and the sensing object is 5mm approx. (DS-L24H: 14mm approx.).

Optimum sensitivity setting distance: 5mm for DS-L10H 14mm for DS-L24H

· If the distance between the sensing object and the background is 7mm or less (DS-L24H: 25mm or less), set at the maximum sensing distance for the object.

· Procedure for setting maximum sensing distance

- (1) Set the span adjuster at the maximum position.
- Place the sensing object at the sensing position. Bring the sensor head near the sensing object gradually, and while seeing the amplifier's operation indicator, find out the position where the sensor enters the Light state. Fix the sensor head at this place. (Move the sensor head carefully.)
- 3 Check the sensor operation, ON with a sensing object and OFF without it. (If the operation is not stable, perform the step 2 again.)
- 4 If the above steps do not provide stable operation, follow the procedure given below using the span adjuster.



Reference chart

Approx. relation between the sensing object and the maximum sensing distance

Sensing object	DS-L10 DS-L10H	DS-L24H
White non-glossy paper	10.0 ± 1.5mm	30 ± 4 mm
Black non-glossy paper (Lightness: 2)	9.5 ± 1.5mm	29 ± 3mm
Aluminum-coated mirror	10.5 ± 1.5mm	30 ± 4 mm
Silicon wafer	7 to 11mm	26 to 36mm

Note: The values in the above table are for reference only and may differ according to the condition of the sensing object.

· Adjustment with span adjuster

The span adjuster enables fine adjustment of the maximum sensing distance.

However, it may be ineffective if the sensing object surface is specular.

Adjustment

① Without the sensing object, gradually turn the span adjuster counterclockwise from the maximum point to the point (A) at which the sensor enters into the Dark

If the sensor does not enter into the Dark state, move the background away from the sensing area, or make it non-glossy black.

- 2 Place the sensing object at the sensing position, and check that the sensor enters into the
- Light state. 3 Turn the adjuster gradually counter-
- clockwise to the point ® at which the sensor enters into the Dark state again.

If the sensor does not enter into the Dark state even if fully turned, the $\mbox{minimum point is the point } \mbox{\mathbb{B}}.$



4 Set the adjuster at the center position between the points (A) and (B), which is the optimum position.

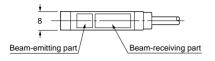
• Do not use during the initial transient time (50ms) after the power supply is switched on.

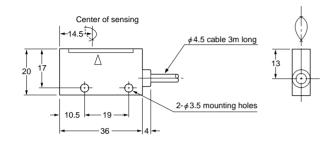
DS

DIMENSIONS (Unit: mm)

DS-L10

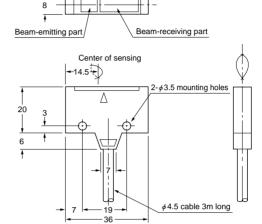
Sensor head





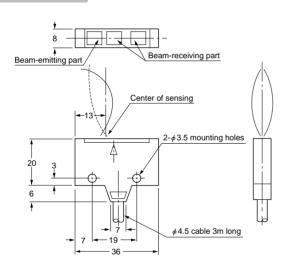
DS-L10H

Sensor head



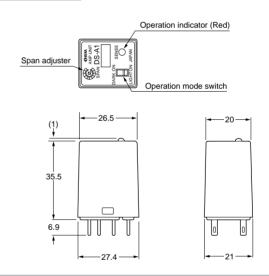
DS-L24H

Sensor head



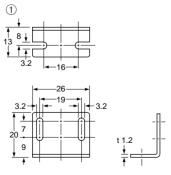
DS-A1

Amplifier

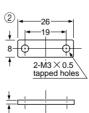


MS-DS-1

Sensor head mounting bracket (Accessory)



Material: Cold rolled carbon steel (SPCC) Two M3 (length 14mm) screws with washers are attached.



Assembly dimensions

Mounting drawing with DS-L24H

